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Kind regards,

Team Nexperia

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

Rev. 03 — 1 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP/PNP resistor-equipped transistors

Table 1.	Product	overview

Type number	Package		NPN/PNP	NPN/NPN
	NXP	JEITA	complement	complement
PEMB17	SOT666	-	PEMD17	PEMH17
PUMB17	SOT363	SC-88	PUMD17	PUMH17

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place cost

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replacement of general-purpose transistors in digital applications

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-50	V
lo	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.37	0.47	0.57	



1

| | 2 3 *006aaa212*

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Symbol
1	GND (emitter) TR1		
2	input (base) TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

3. Ordering information

Table 4. Ordering information				
Package				
Name	Description	Version		
-	plastic surface mounted package; 6 leads	SOT666		
SC-88	plastic surface mounted package; 6 leads	SOT363		
	Package Name -	Package Name Description - plastic surface mounted package; 6 leads		

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PEMB17	5M
PUMB17	B*8

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V _{CBO}	collector-base voltage	open emitter	-	-50	V
V _{CEO}	collector-emitter voltage	open base	-	-50	V
V _{EBO}	emitter-base voltage	open collector	-	-10	V
VI	input voltage				
	positive		-	+10	V
	negative		-	-40	V
lo	output current (DC)		-	-100	mA
I _{CM}	peak collector current		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363		<u>[1]</u> -	200	mW
	SOT666		<u>[1] [2]</u> _	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT363		<u>[1]</u> -	300	mW
	SOT666		[1] [2] _	300	mW

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, standard footprint.

[2] Reflow soldering is the only recommended soldering method.

6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	stor					
R _{th(j-a)}	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$				
	SOT363		<u>[1]</u> -	-	625	K/W
	SOT666		[1] [2] _	-	625	K/W
Per device	9					
R _{th(j-a)}	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$				
	SOT363		<u>[1]</u> _	-	416	K/W
	SOT666		[1] [2] _	-	416	K/W

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, standard footprint.

[2] Reflow soldering is the only recommended soldering method.

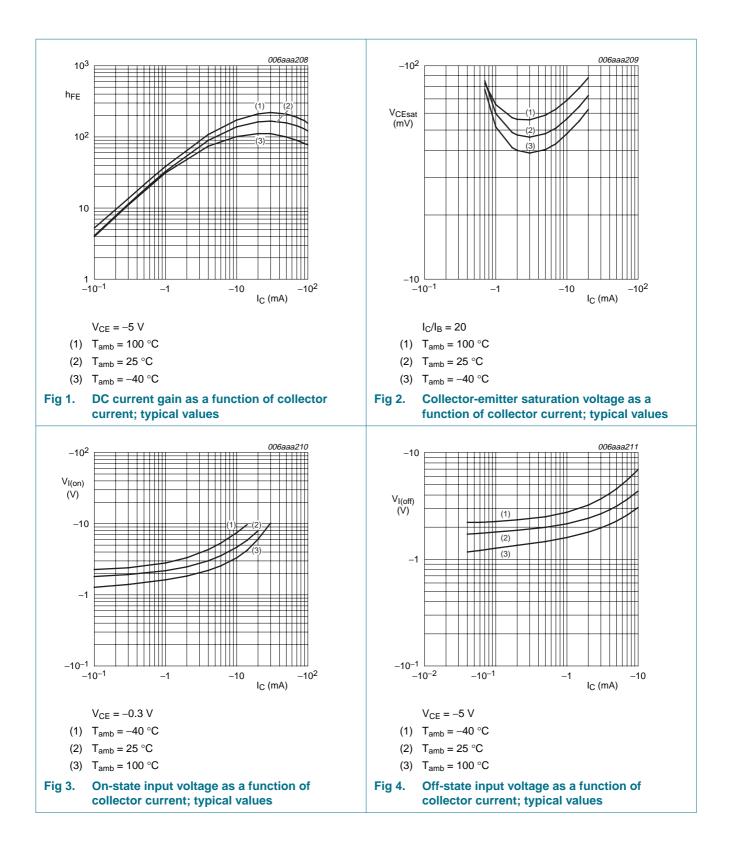
7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transis	stor					
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter	$V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	-1	μA
	cut-off current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C	-	-	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-110	μA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$	60	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -10$ mA; $I_{B} = -0.5$ mA	-	-	-150	mV
V _{I(off)}	off-state input voltage	V_{CE} = -5 V; I_C = -100 μ A	-	-1.7	-1.2	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I _C = -2 mA	-4	-2.7	-	V
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.37	0.47	0.57	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF

NXP Semiconductors

PEMB17; PUMB17

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω



PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

8. Package outline

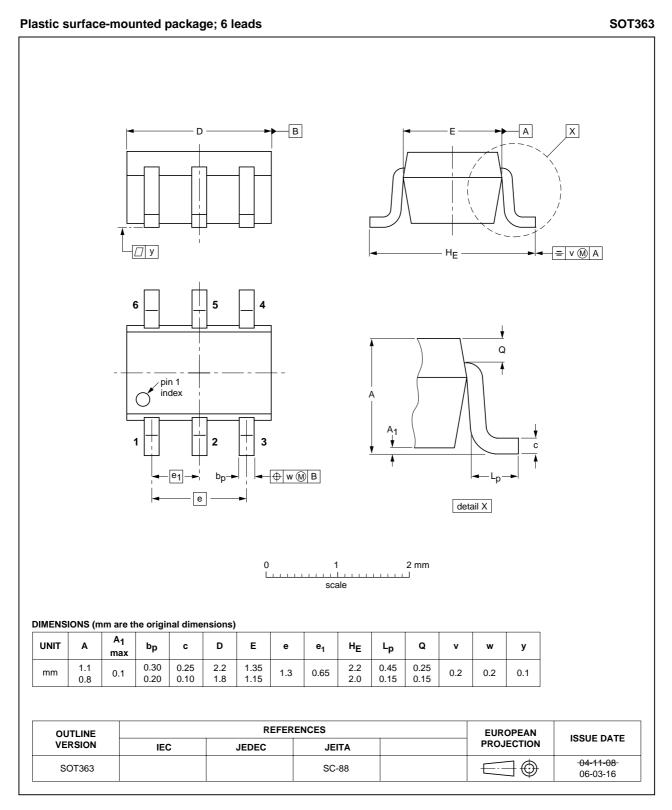


Fig 5. Package outline SOT363 (SC-88)

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

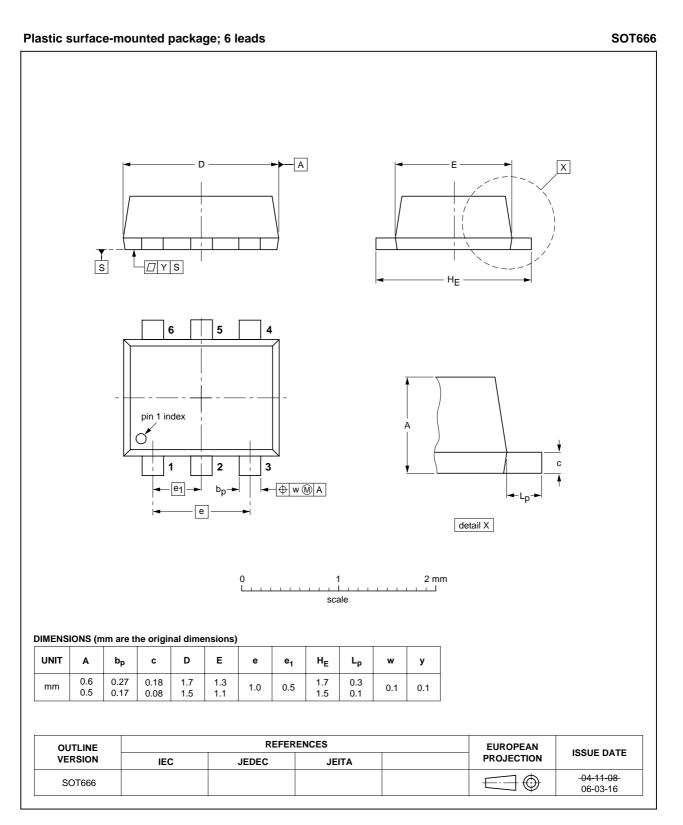


Fig 6. Package outline SOT666

PEMB17_PUMB17_3 Product data sheet

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing q	uantity	
			3000	4000	10000
PEMB17	SOT666	4 mm pitch, 8 mm tape and reel;	-	-115	-
PUMB17	SOT363	4 mm pitch, 8 mm tape and reel; T1	^[2] -115	-	-135
PUMB17	SOT363	4 mm pitch, 8 mm tape and reel; T2	^[3] -125	-	-165

[1] For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping

10. Revision history

Table 10. Revision his	story				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PEMB17_PUMB17_3	20090901	Product data sheet	-	PEMB17_PUMB17_2	
Modifications:		eet was changed to reflect w legal definitions and disc	• •		
	 Figure 5 "Package outline SOT363 (SC-88)": updated 				
	 Figure 6 "Pa 	ckage outline SOT666": up	dated		
PEMB17_PUMB17_2	20050203	Product data sheet	-	PUMB17_1	
PUMB17_1	20031103	Product specification	-	-	

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PEMB17_PUMB17_3
Product data sheet

NXP Semiconductors

PEMB17; PUMB17

PNP/PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = 22 k Ω

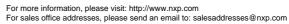
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Date of release: 1 September 2009 Document identifier: PEMB17_PUMB17_3

